

Docket No.: 050432-0657



PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of	:	Customer Number: 20277
MARK T. RAMSBEY, et al.	:	Confirmation Number: 9931
Application No.: 10/718,707	:	Group Art Unit: 2822
Filed: November 24, 2003	:	Examiner: Duong, Khanh B.

For: METHODS FOR FORMING NITROGEN-RICH REGIONS IN NON-VOLATILE SEMICONDUCTOR MEMORY DEVICES (As Amended)

COMMENTS ON STATEMENT OF REASONS FOR ALLOWANCE

Mail Stop Issue Fee
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Please enter the following remarks in response to the Examiner's Comments On Statement of Reasons for Allowance that accompanied the Notice of Allowance dated August 11, 2005.